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1. The importance of distributed grounding in combination with porous Si trenches for the reduction of I_{p/sup} - Si substrate

Han-Su Kim; Kyuchul Chong; Ya-Hong Xie; Jenkins, K.A.;

Electron Device Letters, IEEE

Volume 24, Issue 10, Oct. 2003 Page(s):640 - 642

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2. Effective crosstalk isolation through p⁺ Si substrates with semi-insulating porous Si

Han-Su Kim; Jenkins, K.A.; Ya-Hong Xie;

Electron Device Letters, IEEE

Volume 23, Issue 3, March 2002 Page(s):160 - 162

[AbstractPlus](#) | [References](#) | [Full Text: PDF\(201 KB\)](#) IEEE JNL



3. A porous Si based novel isolation technology for mixed-signal integrated circuits

Han-Su Kim; Kyuchul Chong; Ya-Hong Xie; Devincenzo, M.; Itoh, T.; Becker, A.J.; Jenkins, K.A.;

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